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podzespoly-elektroniczne.pl

MJE15031G;ON;TO220; tranzystor; PNP;8A;150V;50W;30MHz;Pbf



Dane techniczne:

Nazwa: MJE15031G

Typ tranzystora: bipolarny

Kierunek przewodnictwa: PNP

Prąd kolektora: 8A

Napięcie kolektor-emiter: 150V

Moc: 50W

Częstotliwość: 30MHz

Montaż: przewlekany(THT)

Obudowa: TO220

Producent: ON

www.podzespoly-elektroniczne.pl

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sklep@podzespoly-elektroniczne.pl

MJE15028, MJE15030 (NPN), MJE15029, MJE15031 (PNP)

Complementary Silicon Plastic Power Transistors

These devices are designed for use as high-frequency drivers in audio amplifiers.

Features

- High Current Gain – Bandwidth Product
- TO-220 Compact Package
- These Devices are Pb-Free and are RoHS Compliant*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage MJE15028G, MJE15029G MJE15030G, MJE15031G	V_{CEO}	120 150	Vdc
Collector-Base Voltage MJE15028G, MJE15029G MJE15030G, MJE15031G	V_{CB}	120 150	Vdc
Emitter-Base Voltage	V_{EB}	5.0	Vdc
Collector Current – Continuous	I_C	8.0	Adc
Collector Current – Peak	I_{CM}	16	Adc
Base Current	I_B	2.0	Adc
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	50 0.40	W W/ $^\circ\text{C}$
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	2.0 0.016	W W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-65 to +150	$^\circ\text{C}$

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Characteristics	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	2.5	$^\circ\text{C/W}$
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	62.5	$^\circ\text{C/W}$

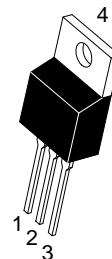
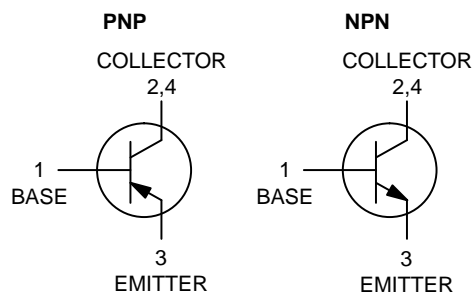
*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



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8 AMPERE POWER TRANSISTORS COMPLEMENTARY SILICON 120-150 VOLTS, 50 WATTS



TO-220
CASE 221A
STYLE 1

MARKING DIAGRAM



MJE150xx = Device Code
x = 28, 29, 30, or 31
A = Assembly Location
Y = Year
WW = Work Week
G = Pb-Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

MJE15028, MJE15030 (NPN), MJE15029, MJE15031 (PNP)

ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector-Emitter Sustaining Voltage (Note 1) ($I_C = 10\text{ mAdc}$, $I_B = 0$) MJE15028, MJE15029 MJE15030, MJE15031	$V_{CEO(sus)}$	120 150	– –	Vdc
Collector Cutoff Current ($V_{CE} = 120\text{ Vdc}$, $I_B = 0$) MJE15028, MJE15029 ($V_{CE} = 150\text{ Vdc}$, $I_B = 0$) MJE15030, MJE15031	I_{CEO}	– –	0.1 0.1	mAdc
Collector Cutoff Current ($V_{CB} = 120\text{ Vdc}$, $I_E = 0$) MJE15028, MJE15029 ($V_{CB} = 150\text{ Vdc}$, $I_E = 0$) MJE15030, MJE15031	I_{CBO}	– –	10 10	μAdc
Emitter Cutoff Current ($V_{BE} = 5.0\text{ Vdc}$, $I_C = 0$)	I_{EBO}	–	10	μAdc

ON CHARACTERISTICS (Note 1)

DC Current Gain ($I_C = 0.1\text{ Adc}$, $V_{CE} = 2.0\text{ Vdc}$) ($I_C = 2.0\text{ Adc}$, $V_{CE} = 2.0\text{ Vdc}$) ($I_C = 3.0\text{ Adc}$, $V_{CE} = 2.0\text{ Vdc}$) ($I_C = 4.0\text{ Adc}$, $V_{CE} = 2.0\text{ Vdc}$)	h_{FE}	40 40 40 20	– – – –	–
DC Current Gain Linearity (V_{CE} From 2.0 V to 20 V, I_C From 0.1 A to 3 A) (NPN to PNP)	h_{FE}	Typ 2 3		
Collector-Emitter Saturation Voltage ($I_C = 1.0\text{ Adc}$, $I_B = 0.1\text{ Adc}$)	$V_{CE(sat)}$	–	0.5	Vdc
Base-Emitter On Voltage ($I_C = 1.0\text{ Adc}$, $V_{CE} = 2.0\text{ Vdc}$)	$V_{BE(on)}$	–	1.0	Vdc

DYNAMIC CHARACTERISTICS

Current Gain – Bandwidth Product (Note 2) ($I_C = 500\text{ mAdc}$, $V_{CE} = 10\text{ Vdc}$, $f_{test} = 10\text{ MHz}$)	f_T	30	–	MHz
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Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Pulse Test: Pulse Width $\leq 300\text{ }\mu\text{s}$, Duty Cycle $\leq 2.0\%$.
2. $f_T = |h_{fe}| \cdot f_{test}$.

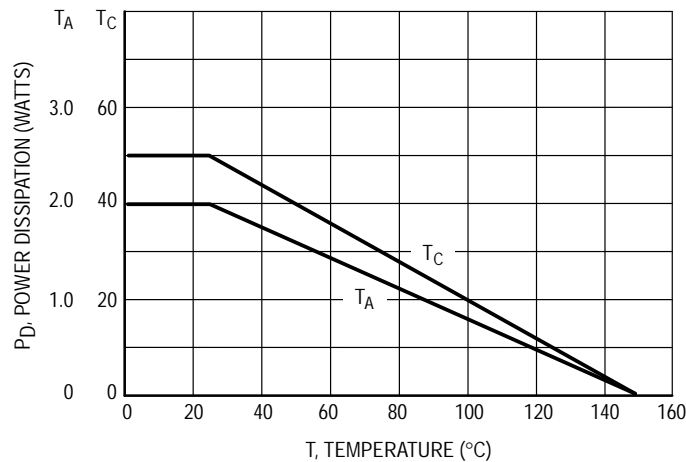


Figure 1. Power Derating

MJE15028, MJE15030 (NPN), MJE15029, MJE15031 (PNP)

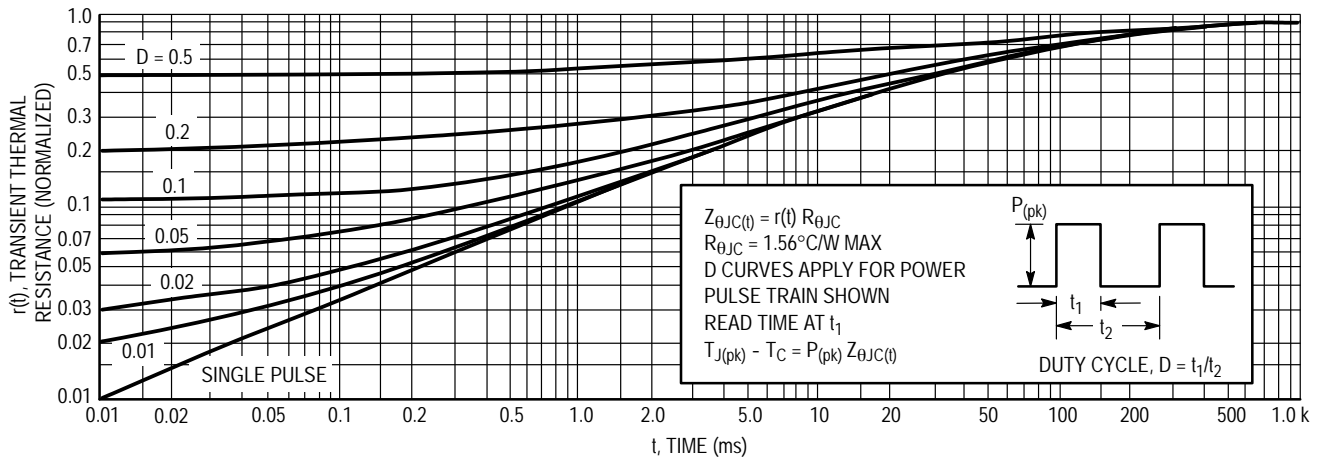


Figure 2. Thermal Response

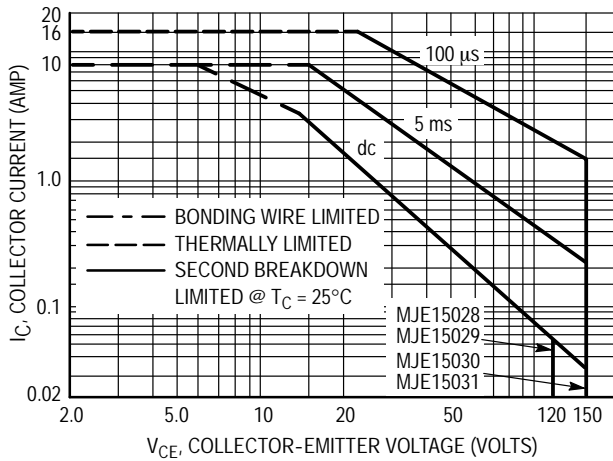


Figure 3. Forward Bias Safe Operating Area

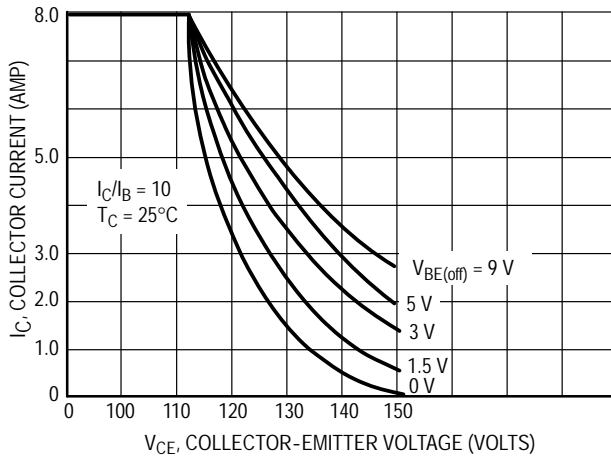


Figure 4. Reverse-Bias Switching Safe Operating Area

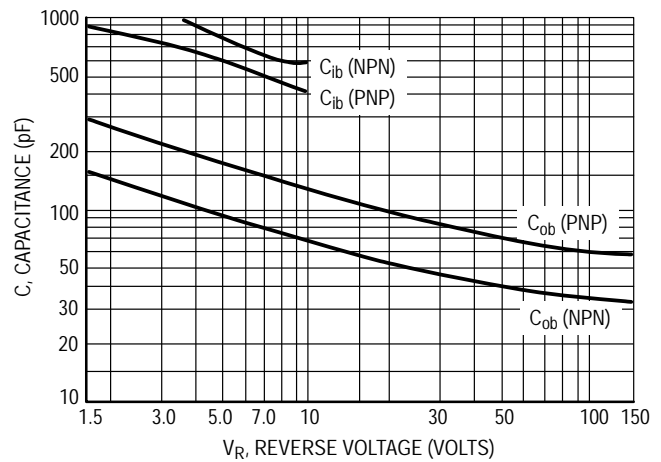


Figure 5. Capacitances

MJE15028, MJE15030 (NPN), MJE15029, MJE15031 (PNP)

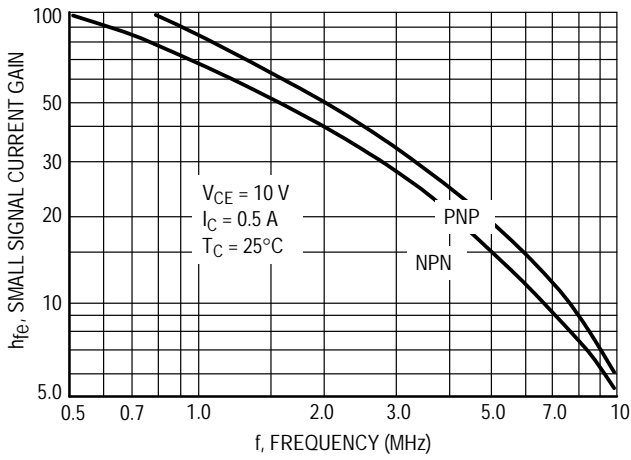


Figure 6. Small-Signal Current Gain

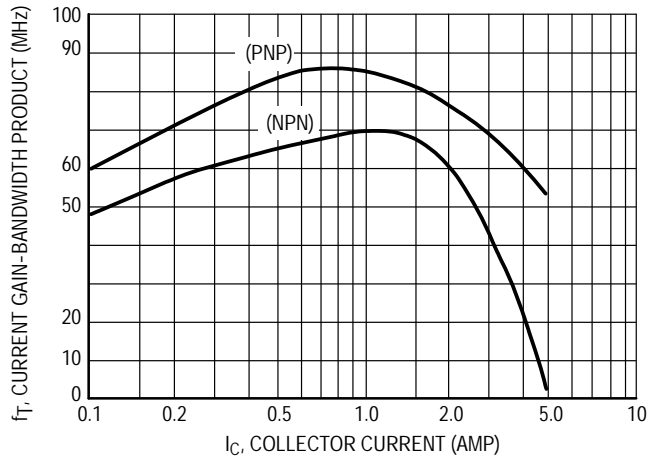
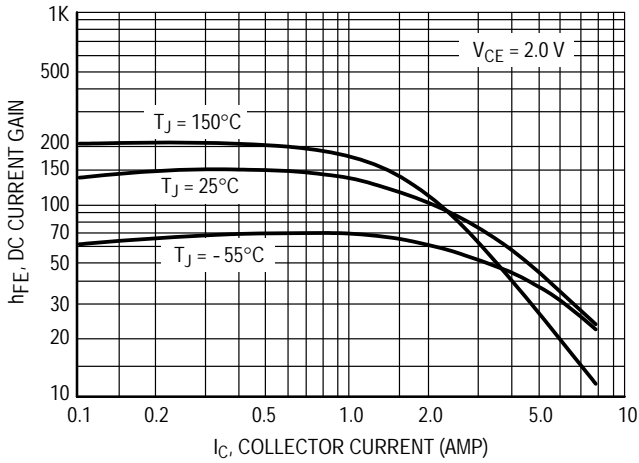


Figure 7. Current Gain-Bandwidth Product

NPN — MJE15028 MJE15030



PNP — MJE15029 MJE15031

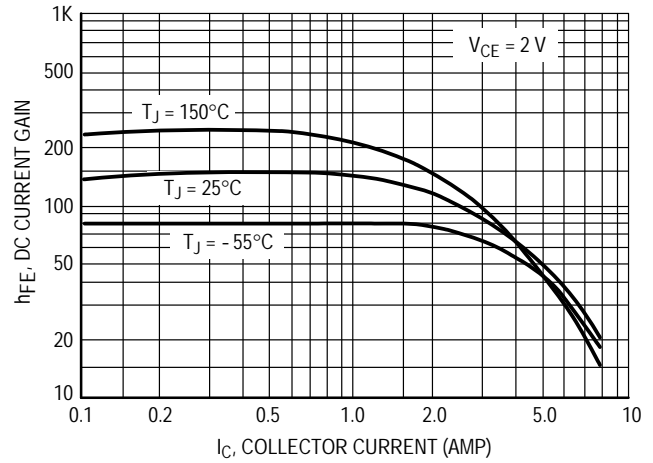
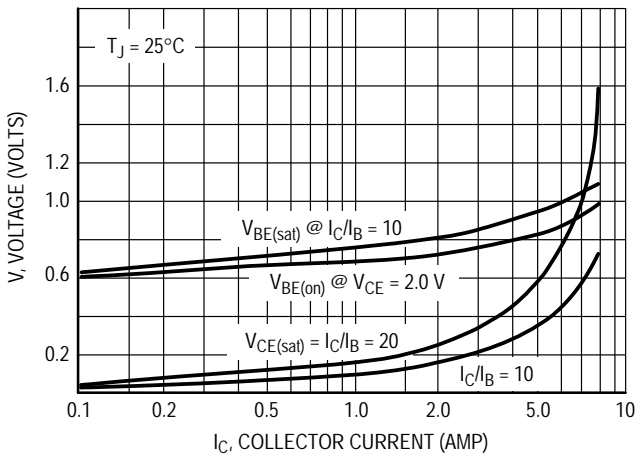


Figure 8. DC Current Gain

NPN



PNP

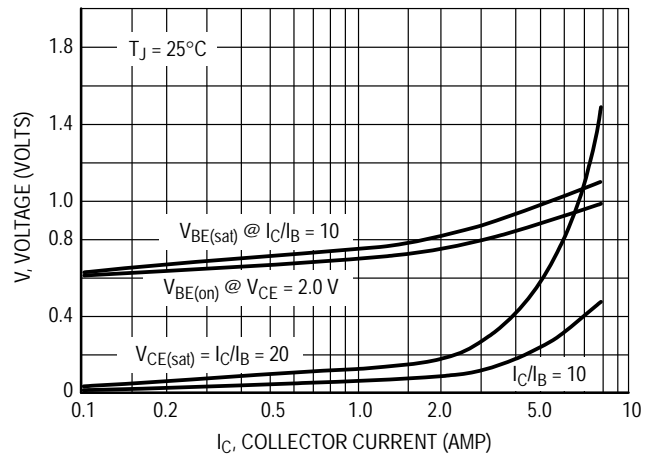


Figure 9. "On" Voltage

MJE15028, MJE15030 (NPN), MJE15029, MJE15031 (PNP)

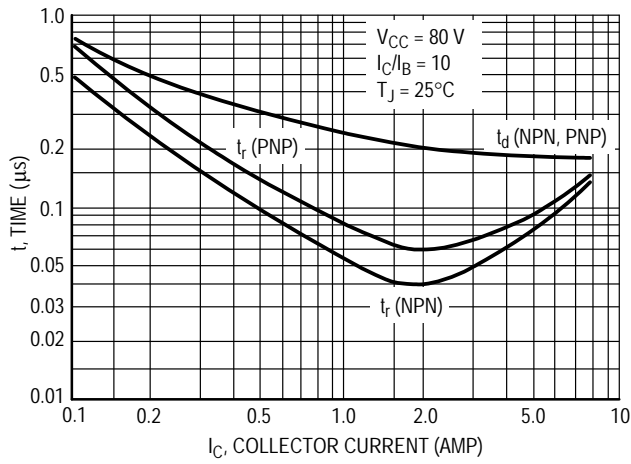


Figure 10. Turn-On Times

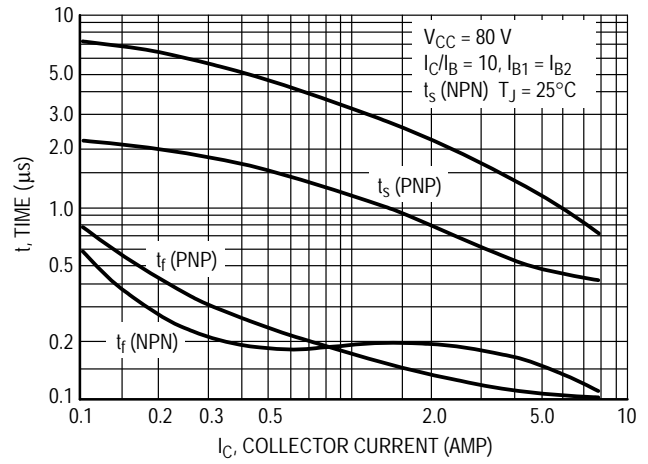


Figure 11. Turn-Off Times

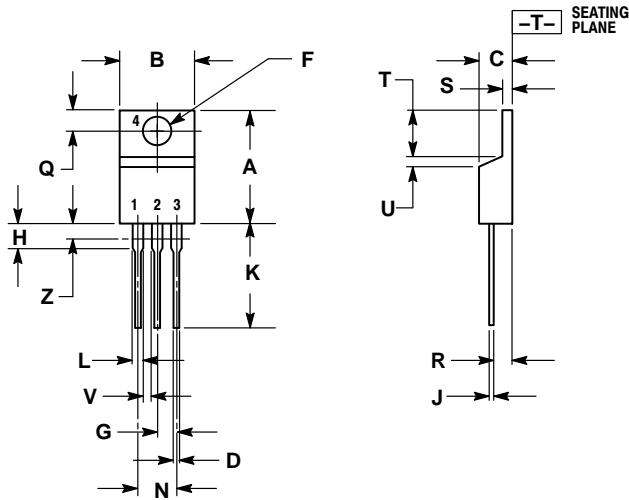
ORDERING INFORMATION

Device	Package	Shipping
MJE15028G	TO-220 (Pb-Free)	50 Units / Rail
MJE15029G	TO-220 (Pb-Free)	50 Units / Rail
MJE15030G	TO-220 (Pb-Free)	50 Units / Rail
MJE15031G	TO-220 (Pb-Free)	50 Units / Rail

MJE15028, MJE15030 (NPN), MJE15029, MJE15031 (PNP)

PACKAGE DIMENSIONS

TO-220
CASE 221A-09
ISSUE AH



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.570	0.620	14.48	15.75
B	0.380	0.415	9.66	10.53
C	0.160	0.190	4.07	4.83
D	0.025	0.038	0.64	0.96
F	0.142	0.161	3.61	4.09
G	0.095	0.105	2.42	2.66
H	0.110	0.161	2.80	4.10
J	0.014	0.024	0.36	0.61
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
V	0.045	---	1.15	---
Z	---	0.080	---	2.04

STYLE 1:

- PIN 1: BASE
2. COLLECTOR
3. EMITTER
4. COLLECTOR

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